

■Features

•Emission wavelength: 4.33 μm (Typ.)

Output power: 20 mW (Min.)

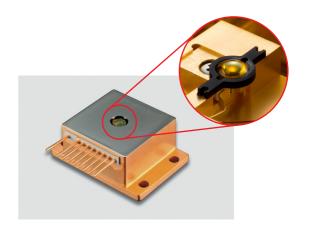
 Built-in aspherical colimation lens eliminates the need for optical alignment

Low-reflectivity beam exit window (ZnSe)

* Please contact a Hamamatsu sales office for the availability of the other wavelength above.



Trace gas analysis (CO₂, CO_{2 isotope})



Outline

The lens integrated package for DFB-CW type QCL is sealed and collimated housing. Internal lens provides collimated output beam radiation. TEC (peltier) and thermistor for temperature stabilization of QCL-laser chip are inside the housing. The lens integrated package allows to use under good usability without beam alignment of invisible mid-infrared laser.

Absolute maximum rating

T_{op(qcl)} =+20 °C, unless otherwise specified.

Characteristic	Symbol	Rating	Unit
Forward current *1)	I _{f max}	This product has individual difference.	Α
Forward voltage *1)	V_{fmax}	Confirm data sheet attached to a product *2)	V
Reverse voltage *1)	V_{r}	0.0	V
Rise time of forward current *3)	t _r	>400	μs
Fall time of forward current *4)	t _f	>400	μs
TEC current (cooling mode) *5)	I _c	+3.7	Α
TEC current (heating mode) *5)	IC	-1.5	Α
TEC voltage	Vc	±13.0	V
Operating temperature (case) *6) *7)	$T_{op(c)}$	+10 to +60	°C
Operating temperature (QCL) *6) *8)	$T_{op(qcl)}$	+5 to +55	°C
Change speed of operating temperature *9)	-	10 *10)	°C/min
Storage temperature *6)	T _{stg}	-20 to +65	°C

^{*1)} Confirm data sheet attached to a product. Sensitive to electrical surges and instability. Reverse current/voltage cause damage in laser specifications and out of warranty.

^{*2)} Necessary specifications of power supply : I₁≥1.3 A, V₁≥16 V

^{*3)} Rise time from sub-threshold to 90 % of the absolute maximum rating of (I_{I max}). Using this product when rise time of forward current is faster than 400 μs from sub-threshold to 90 % of the absolute maximum rating of (I_{I max}) may cause serious and irreparable damage to this product.

^{*4)} Fall time from 90 % of the absolute maximum rating of (I_{rmax}) to sub-threshold.

Using this product when fall time of forward current is faster than 400 μs from 90 % of the absolute maximum rating of (I_{rmax}) to sub-threshold may cause serious and irreparable damage to this product.

^{*5)} Even if TEC current (Ic) is below the absolute maximum, insufficient heat dissipation from this product may cause damage in laser and TEC specifications and out of warranty. Especially there are possibilities of damage, degradation and less reliability when TEC is operated in heating mode since heated-up side (laser chip) is thermally isolated from case of package and ambience.

^{*6)} Avoid water condensation.

^{*7)} Temperatures of case (body) of HHL-package.

^{*8)} Temperatures of QCL-laser when operated; should be monitored by the built-in thermistor for Top(qcl).

^{*9)} Speed when changing the temperature (Top(qcl)) controlled by the built-in TEC.

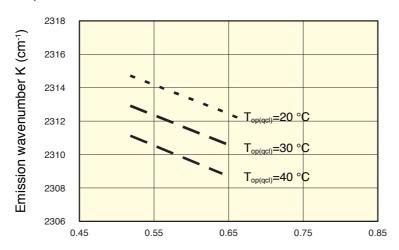
^{*10)} In conditions of temperature range of the $(T_{op(qcl)}) \ge 5$ °C.

■Specification (laser)

Characteristic	Symbol	Condition	Min.	Тур.	Max.	Unit
Operating temperature (QCL) *1)	$T_{op(qcl)}$	K *2)=2310 cm ⁻¹	+10	-	+50	°C
Spectral linewidth *3)	ΔK_L	K *2)=2310 cm-1	-	-	0.2 *4)	cm ⁻¹
Wavenumber tuning range by forward current *5) *6)	ΔKc	10 °C ≤ T _{op(qcl)} ≤ 50 °C	±0.5	-	-	cm ⁻¹
Wavenumber tuning range by operating temperature *5) *7)	ΔK_T	$I_{th} < I_f < I_{f max}$	±1.0	-	-	cm ⁻¹
Radiant power	фе	K *2)=2310 cm-1	20	-	-	mW
Threshold current	I _{th}	T _{op(qcl)} =+20 °C	-	-	1.0	А
Side mode suppression ratio	SMSR	T _{op(qcl)} =+20 °C	25 *4)	-	-	dB

^{*1)} This product is able to emit the target wavenumber at a certain Top(qc) within the specified temperature range.

■ Characteristics examples



Forward current If (A)

Characteristic	Symbol	Condition	Typical value
Temperature coefficient of wavenumber *1)	δK_T	I _f fixed	−0.18 cm ⁻¹ /°C
Current coefficient of wavenumber *1)	δK _C	T _{op(qcl)} fixed	−0.017 cm ⁻¹ /mA

^{*1)} This product has individual difference. Confirm data sheet attached to a product.

TEC

Characteristic	Symbol	Condition	Specification
Maximum temperature difference	ΔT_{max}	$T_h=27$ °C, in N_2 , $Q_c=0$, $I_c=+3.7$ A	>40 °C
Maximum heat pumping capacity	Q _{c max}	$T_h= 27 ^{\circ}C$, in N_2 , $I_c=+3.7 A$, $\Delta T=0$	>18 W
AC resistance	ACR	T _h =27 °C, I _c =0.1 mA, 1 kHz	2.0 Ω±0.4 Ω

Note) ΔT : Temperature difference

Q: Heat pumping capacity

^{*2)} K: Emission wavenumber (cm-1)

^{*3)} FWHM.

^{*4)} These values are limited by resolution and signal-to-noise ratio of instrument when tested.

^{*5)} Center of the tuning range is the emission wavenumber (K).

^{*6)} At fixed $T_{op(qcl)}$ specified in the condition. Variable range of I_f for tuning: $I_{th} < I_f < I_{f max}$.

^{*7)} At fixed I_f specified in the condition. Variable range of $T_{op(qcl)}$ for tuning: 10 °C $\leq T_{op(qcl)} \leq 50$ °C.

Ic: TEC current

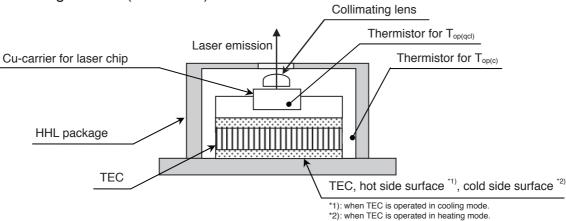
T_h: Temperature of TEC's hot side surface (TEC: cooling mode)

Thermistor

Characteristic	Symbol	Condition	Specification
Resistance	R ₂₅	25 °C	10 kΩ±2.5 %
Beta value	В	0 °C / 100 °C	3450 K

Note) Same specifications for both thermisters of $T_{\text{op(qcl)}}$ and $T_{\text{op(c)}}$.

Thermistors configurations (schematic)



■Window of HHL package

Characteristic		Specification
Material ZnSe, Plano-Plano		ZnSe, Plano-Plano
Dimension	Clear aperture *1)	φ4.4 mm
	Thickness	0.7 mm
Coating	Coating	BBAR, both surface

^{*1)} Mechanical aperture of HHL package

Output beam

Characteristic	Symbol	Condition	MIn.	Тур.	Max.	Unit
Beam spread angle *1) *2)	θ	T _{op(qcl)} =+20 °C	0	3	5	mrad
Beam waist position *1) *3)	Z_{w0}	T _{op(qcl)} =+20 °C	50	-	1000	mm
Beam waist width *1) *4)	W ₀	T _{op(qcl)} =+20 °C	0.5	1.5	3	mm

^{*1)} This product has individual difference. Confirm data sheet attached to a product.

Necessary specifications of power supply for the laser (QCL)

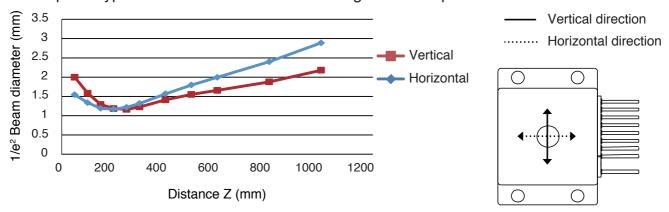
Characteristic Specification	
Output current	≥1.3 A
Output voltage	≥16 V
Function	Surge protect
Function	Constant current control

^{*2)} Half angle. Larger spread angle either vertical direction (vertical to pins of package) or horizontal direction (horizontal to pins of package).

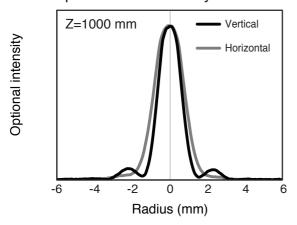
^{*3)} From package top surface.

^{*4) 1/}e² beam diameter.

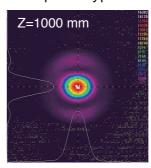
Example of typical characteristics of beam divergence of output beam



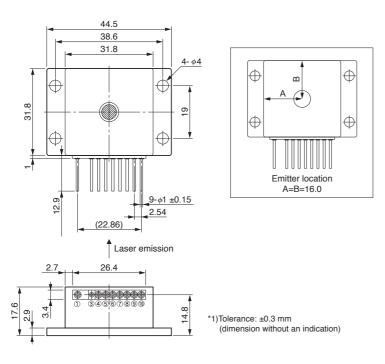
Example of beam intensity distribution



Example of typical beam profile



■Dimensional outline (unit: mm)



Pin No. *2)	Function
1	TEC cathode (-)
3	N.C.
4	QCL anode (+)
(5)	Thermistor (T _{op(qcl)})
6	Thermistor (T _{op(qcl)})
7	QCL cathode (-)
8	Thermistor (T _{op(c)})
9	Thermistor (T _{op(c)})
10	TEC anode (+)

^{*2)} Pin of ③ is electrically connected to the case; package body. Other all pins are floating to the case.

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